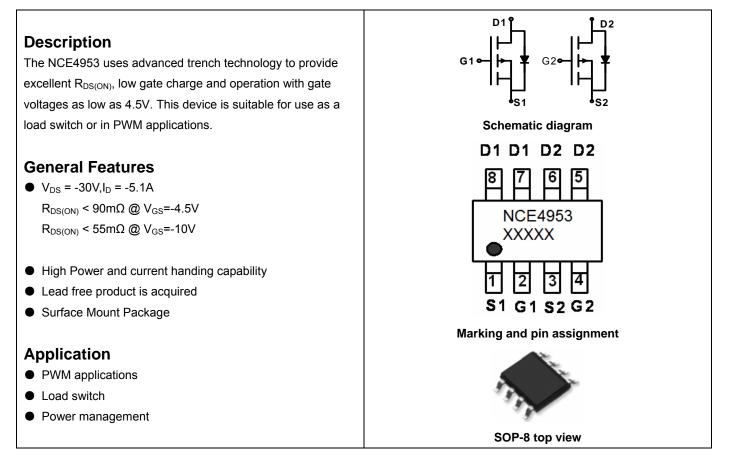


# NCE P-Channel Enhancement Mode Power MOSFET



## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE4953	NCE4953	SOP-8	Ø330mm	12mm	4000 units

## Absolute Maximum Ratings (T<sub>A</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	-30	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	I <sub>D</sub>	-5.1	A	
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	-20	A	
Maximum Power Dissipation	PD	2.5	W	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C	

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>θJA</sub>	50	°C <b>/W</b>
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### Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						



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Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250µA	-30	-33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-24V,V <sub>GS</sub> =0V	-	-	-1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	L					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=-250\mu A$	-1.1	-1.6	-2.1	V
	_	V <sub>GS</sub> =-10V, I <sub>D</sub> =-5.1A	-	43	55	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4.2A	-	62	90	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =-15V,I <sub>D</sub> =-4.5A	4	7	-	S
Dynamic Characteristics (Note4)					l.	
Input Capacitance	C <sub>lss</sub>		-	520	-	PF
Output Capacitance	C <sub>oss</sub>	- V <sub>DS</sub> =-15V,V <sub>GS</sub> =0V, F=1.0MHz	-	130	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	70	-	PF
Switching Characteristics (Note 4)	·			•		
Turn-on Delay Time	t <sub>d(on)</sub>		-	7	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =-15V, ID=-1A,	-	13	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =-10V,R <sub>GEN</sub> =6Ω	-	14	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	9	-	nS
Total Gate Charge	Qg		-	11	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-15V,I <sub>D</sub> =-5.1A,V <sub>GS</sub> =-10V	-	2.2	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	]	-	3	-	nC
Drain-Source Diode Characteristics	-			•		
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-5.1A	-	-	-1.2	V

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production



# **Typical Electrical and Thermal Characteristics**

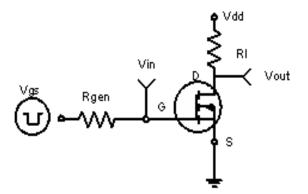
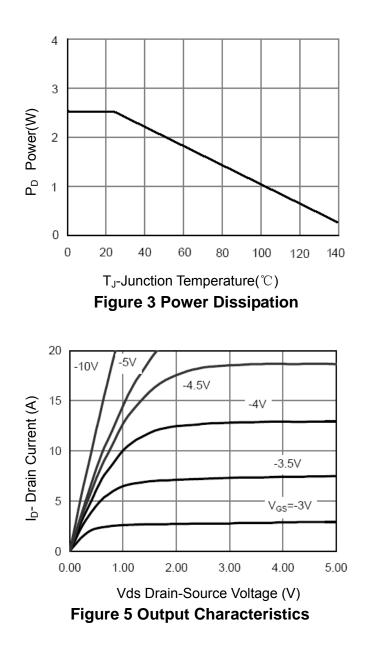
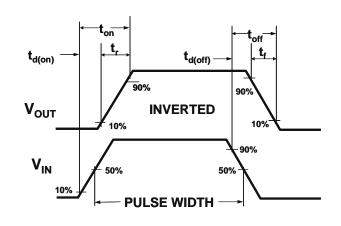
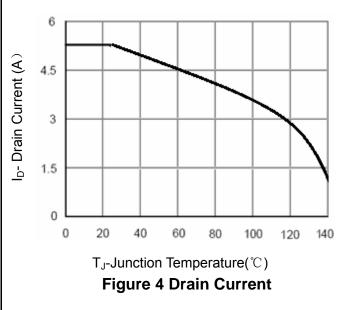


Figure 1:Switching Test Circuit









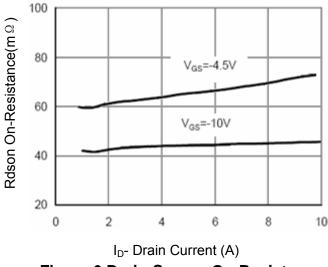
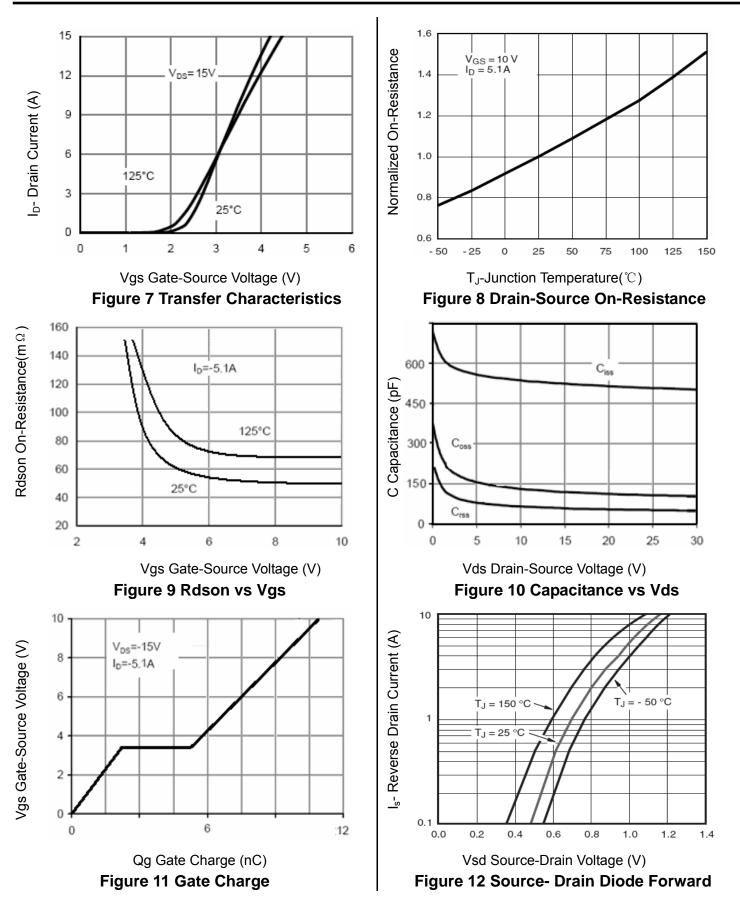


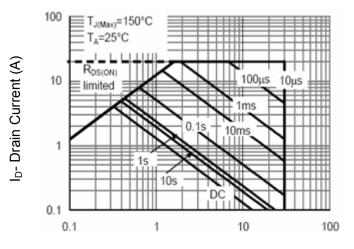
Figure 6 Drain-Source On-Resistance



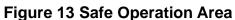
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Vds Drain-Source Voltage (V)



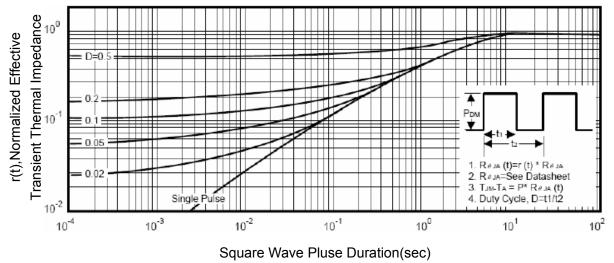
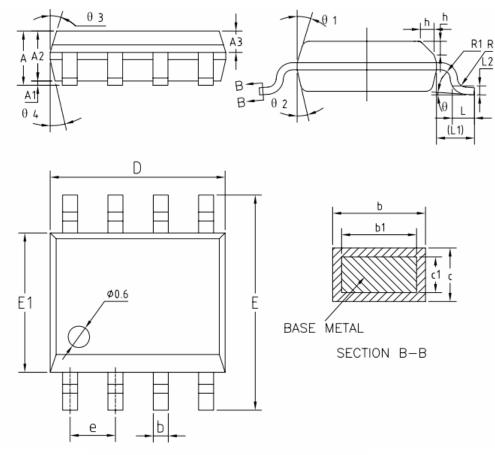


Figure 14 Normalized Maximum Transient Thermal Impedance



# **SOP-8 Package Information**



#### COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
Α	1.35	1.55	1.75
A1	0.10	0.15	0.25
A2	1.25	1.40	1.65
A3	0.50	0.60	0.70
b	0.38	-	0.51
b1	0.37	0.42	0.47
с	0.18	-	0.25
c1	0.17	0.20	0.23
D	4.80	4.90	5.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.17	1.27	1.37
L	0.45	0.60	0.80
L1		1.04REF	
L2		0.25BSC	
R	0.07	-	-
R1	0.07	-	-
h	0.30	0.40	0.50
θ	0.	-	8*
θ <sub>1</sub>	15	17	19*
θ2	11.	13*	15*
03	15 <b>'</b>	17	19*
θ4	11'	13*	15*



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